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Resistance measurements and weak localisation in long SWNTs

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In many I-V measurements, evidence has emerged pointing towards the existence of Luttinger-liquid behaviour in metallic single-walled carbon nanotubes (SWNTs), as expected for strongly interacting electrons in 1-d; such behaviour was observed via the power-law temperature and bias voltage dependence of the current through tunnelling contacts attached to the nanotubes. In particular, recent advances in the growth of extremely long nanotubes (>1 mm) have allowed for experimental measurements on the scaling behaviour of resistance in the individual, millimetre long SWNTs for the temperature range of 1.6-300 K. From the linear scaling of resistance, the temperature-dependent electron mean free path has been calculated for each temperature and, beyond the linear scaling regime, it has been observed that the resistance increases exponentially with length, indicating localisation behaviour. In this work, we analyse the results of the resistance measurements of different lengths of SWNT indicating the weak localisation behaviour.

Keywords: quantum transport; weak localisation; carbon nanotube; phase coherence

1. Introduction

The rapidly advancing technology of nanometric devices has led to the production of smaller and smaller systems. Among the main items in the design of these electronic devices are the measurement and understanding of the current–voltage (I-V) response of electronic circuits in which the carbon nanotubes act as conducting elements. These devices, often called mesoscopic systems, are large on the atomic scale but sufficiently small that the electron wave function is coherent over the entire sample; the condition for coherence is that the electrons traverse the wire without undergoing any inelastic collision. Indeed, in a perfect single-walled carbon nanotube (SWNT), electrons propagate ballistically if the inelastic scattering can be neglected.

On the other hand, it is also well known that at low temperatures, charge transport in any disordered conductor is governed by the interplay between inelastic and elastic scattering of static disorder (impurities and defects) of electrons; therefore, in low-dimensional systems like SWNTs, an arbitrarily weak disorder localises [1,2] all single-electron states and there would be no transport without inelastic processes (Anderson localisation of electronic states leads to metal—insulator transition at zero temperature [3]: note that, for electrons in a given conduction band, strong enough disorder can localise the whole band; the metal—insulator transition induced by disorder is called Anderson transition).

Coherent quantum transport in low-dimensional systems can be investigated with either the Kubo or the

Landauer – Buttiker formalism [4]. The first approach, which derives from the fluctuation-dissipation theorem, allows one to evaluate the intrinsic conduction regime within the linear response and gives direct access to the fundamental transport length scales, 2 such as the elastic mean free path l_0 and the localisation length ξ . While l_0 results from elastic backscattering by static disorder, ξ denotes the scale beyond which quantum conductance decays exponentially with the system length L driving the system from weak to strong localisation. In other words, the localisation length ξ gives the scale beyond which weak localisation is fully suppressed, since the quantum interference effects are usually reduced by inelastic scattering as decoherence, owing to mechanisms such as electron–phonon (e–ph) or electron–electron (e–e) coupling. Within the framework of weak localisation theory, it has been possible to derive perturbatively the relationship between the measured conductance which becomes more appropriate, since it rigorously treats G, its quantum correction δG and the coherence length l_{ϕ} that fixes the scale beyond which quantum interference effect is destroyed. The estimation of the coherence length is a central issue in mesoscopic physics, and weak localisation provides an elegant framework to extract the behaviour of l_{ϕ} , which mainly depends on the dimensionality of charge transport. When l_0 becomes longer than the length of the nanotube between the leads, the carriers propagate ballistically and contact effects prevail. In such a situation, the Landauer-Buttiger formalism becomes more appropriate, since it rigorously treats transmission properties for open systems and arbitrary interface geometries.

2. Quantum transport in SWNT

2.1 Conductivity and transport

The more general formula for actual local current measured by experimentalists (generalised Ohm's law) for conductivity in infinite length system is

$$J_{\alpha}(r,t) = \int dr' \sum_{\beta} \sigma_{\alpha\beta}(r,r',\omega) E_{\beta}(r',t), \qquad (1)$$

where the (non-local) conductivity $\sigma_{\alpha\beta}$ is the response to the actual (external + induced) electric field, and is given by the Kubo formula [5] (where periodic boundary conditions and coupling of only the charge degrees of freedom, no spin degree of freedom is considered, to external *E*-field are assumed)

$$\sigma_{\alpha\beta}(r,r',\omega) = \frac{e^2}{\hbar\omega} \int_0^\infty dt e^{i\omega t} \langle \psi | [j_{\alpha}^+(r,t),j_{\beta}(r',0)] | \psi \rangle$$
$$+ \frac{ne^2}{m\omega} i\delta_{\alpha\beta}\delta(r-r'). \tag{2}$$

The wave function ψ is the ground state of the many-body Hamiltonian, which contains all possible interactions in the solid (except the interaction between the total electric field and the particles of the system) and the first term is called the retarded current-current correlation function. Kubo first derived the equations for electrical conductivity in the solid, and the Kubo formulas are the name applied to the correlation function that describes the linear response.

But this procedure is physically incorrect as a way of defining the conductivity in a finite system in which electrons enter from an external electrode at one end and are removed at the other end collected by another external electrode. In a finite (ideal) sample, if the chemical potential is higher at one lead, electrons of the large reservoir with constant μ_1 , than that at the other lead, with constant μ_2 , the current is the response to the gradient of chemical potential for electrons not in the electric field; in other words, if $\mu_1 > \mu_2$ and e are the absolute values of the electronic charge, the voltage difference ΔV between the two baths due to flow across the sample of the current I is

$$\Delta V = \frac{I}{G_c} = \frac{\mu_1 - \mu_2}{e},\tag{3}$$

where

$$G_{\rm c} = \frac{e^2}{\pi \hbar} T(E_{\rm f}) \tag{4}$$

is the irreducible conductance measured between the two outside reservoirs, with T being the transmission probability for channels (to go from electrode 1 to electrode 2). The inelastic processes (which break the

time-reversal invariance and the phase coherence of the states at the two extremities, dissipate energy and restore equilibrium) in this case are assumed to exist only in the two electrons baths, so that the randomised phase of the injected and absorbed electrons through these processes results in no phase relationship between particles.

At a low temperature, in the presence of only elastic scattering for the electrons at the Fermi surface, with a linear series of random scatterers connecting the two reservoirs, the true conductance G due to the barrier (including spin degeneracy) is correctly given by the transmission and reflection coefficients of the sample by the Landauer–Buttiker, not the Kubo, formula [4,5]

$$G = \frac{e^2}{\pi \hbar} \frac{T(E_{\rm F})}{1 - T(E_{\rm F})}.$$
 (5)

Electronic transport measurements [6] on individual SWNT demonstrate that, in the absence of scattering (then the transmission probability is T=1), the momentum relaxation length and the localisation length ξ are much larger than the wire length and the transport in these systems is ballistic: the wave function of the electron is extended over the total length of the nanotube and there are only two channels that contribute to the electronic transport giving $G=2G_{\rm c}$. However, as already outlined, in the presence of some mechanism of scattering, the conductance is described by the Landauer formula (4) and the conductance is no longer exactly quantised.

Because the electron can lose energy and equilibrate with heat bath only via inelastic collisions, it is necessary to re-examine the conventional concept of energy dissipation in a quasi-1-d resistor systems. In the theory of the 1-d electron systems, called the Luttinger liquid (LL) [7,8] (see Appendix A), the correlated electron state is characterised by a parameter g that measures the strength of the interaction between the electrons (g = 1 for the noninteracting electron gas). The most important feature of the LL, in contrast to the Landau Fermi-liquid theory³ (FL), is the absence of the fermion quasi-particle branch at low energy: excited states of the system must be described by the bosonic fluctuations of the charge and spin densities dispersing with different velocities, which correspond to many-body electron state with a huge number of the electron-hole pairs. This has a pronounced effect on the tunnelling into a LL conductor: the I-V curve of a tunnel junction between a normal FL and a LL conductor is expected to be non-ohmic and described by a power law with an exponent depending on interaction strength.

Not only that, Bockrath et al. [9] observed a Luttingerliquid behaviour in (rope of) SWNT's in measurements of the electrical transport as a function of temperature resulting in a power law for linear response conductance

$$G(T) \propto T^{\alpha}$$
, (6)

where $\alpha = f(g)$ and $g = [1 + 2U/\Delta]^{-1/2}$ (*U* is the charging energy of the tube and Δ [10] is the singleparticle level spacing).

Weak localisation

When the temperature is so high that the conductivity can be treated as a local quantity, like in Anderson localisation which deals with the wave function of the single electron in the presence of impurities, the conductance is obtained by the combination of smaller parts of materials. But when the temperature is low or the sample is small, the dephasing length l_{φ} is greater than the sample linear dimensions L so that the quantum corrections to the conductivity are non-local and the conductance can no longer be treated as a self-averaging quantity. Since the lack of self-averaging of the conductance is a feature of mesoscopic conductors, in SWNT it is necessary to analyse the effects of weak disorder and the inelastic scatterings on charge transport.

Due to the existence of the impurities the transport is more diffusive than ballistic (the existence of scattering is possible in both regimes but in diffusive one we have that $l=v_{\mathrm{F}} au\ll L$ so that the material is characterised by a relatively low mobility) though the elastic scattering of the electrons, if these impurities are equivalent to static defects, can modify the interference terms but does not cause decoherence [4]. At low temperature, the conduction take place mainly with electrons at Fermi energy and, due to some gate potential, the Fermi point upon which the electrons travel can be shifted slightly; therefore, it is possible that an electron that moved on one side (path) of an impurity begins to move on the other side (path) after the shift. This process (analogous to the Aharonov-Bohm effect in the presence of some magnetic field) induced a quantum fluctuation of the conductance of the order of $2e^{2}/h$ and depends on the exact configuration of scattering centres within the sample: these two paths are time reversed with respect to one another and since the electron returns to its original position it can interfere with itself creating an additional resistance called weak localisation [11,12]. Then, the weak localisation is caused by the quantum interference effect on the diffusive motion of a single electron.

From the semiclassical point of view, it is possible to calculate this additional resistance considering that the conductivity is related to the current-current correlation function, as in Equation (2), and being $D = v_F^2 \tau$ the diffusion coefficient and $l_{\varphi} = \sqrt{D\tau_{\varphi}}$ for 1D, we get

$$\Delta \sigma_{\rm WL} \approx -\frac{e^2}{\pi \hbar} l_{\varphi} \left[1 - \left(1 + \frac{\tau_{\varphi}}{\tau} \right)^{-1/2} \right].$$
 (7)

Even though it has been suggested in [13] that zero-point fluctuations cause the dephasing in one-dimensional quantum wire at low temperature (ascribed to finite broadening of Fermi surface), and presenting a zero-pointlimited dephasing time τ_0 in good agreement with the measured saturation values τ_{φ} found in many experiments, in [14] this hypothesis is rejected using purely physical arguments.

A more sophisticated theory [15,16] tells us that in the presence of a vector potential A, for $\omega \tau \ll 1$, the probability of a return path in a disordered SWNT can be conveniently obtained by calculating the Cooperon $C_{\omega}(r,r')$, which is a retarded classical electron-electron propagator satisfying a modified diffusion equation in the frequency domain [16]

$$\left[-D \left(\nabla_{\mathbf{r}} - \frac{2ie}{\hbar} \mathbf{A} \right)^{2} + i\omega + \frac{1}{\tau_{\phi}} \right] C_{\omega}(r, r')$$

$$= \delta(r - r'). \tag{8}$$

The WL correction to the conductivity is due to enhanced probability to return, so that

$$\Delta\sigma_{\rm WL}(\omega) = -\frac{2e^2D}{\pi\hbar}C_{\omega}(r,r'). \tag{9}$$

Resistance in long SWNT

The conductance of metallic SWNT has been shown to depend strongly on the nature of the contacts between the nanotube and the leads. In a typical experimental set-up [10], a bias voltage is applied across a nanotube connected to metallic leads, while a gate voltage applied to a third electrode acts as a chemical potential and modulates the charge on the nanotube (see [10], Figures 1, 3 and 4). At room temperature, the main origin of the resistivity at low bias in high-quality metallic SWNT is believed to be the inelastic scattering by acoustic phonon: the scattering is weak resulting in long mean free path in a range from few hundred nanometres to several micrometres both in the measurements and the calculations. Then at low bias regime we get ballistic transport. When sufficiently large bias is applied to drive the electric current, higher energy vibrational modes are activated and e-ph coupling limits ballistic transport: electrons gain enough energy to emit optical or zone boundary phonons leading to a saturation of the current, in [17] indicated at $\sim 20 \,\mu\text{A}$. The effect of electron-(optical) phonon coupling was found to strongly affect electronic conductance and to induce some energy dependence of the coherence length scale, completely similar to the experimental data obtained in the weak localisation regime [18,19].

4. Conclusion

We study the suppression of the quasi-ballistic conduction in long (many l_{φ}) SWNT noting that some environmental conditions also at low temperature introduce some dynamic disorder, which involves, by means of inelastic scattering [18–20], a weak localisation correction to the conductance.

Notes

- The localisation is a property of the states in random QM systems and can be interpreted by total back reflection of particles from potential barriers so that they become localised in a single potential well.
- 2. Important length scales: the coherence length l_{ϕ} , the energy relaxation length l, the elastic mean free length l_0 , the Fermi wave length $\lambda_{\rm F}$ of the electron, the sample size L: in mesoscopic systems it will be $\lambda_{\rm F} \leq l_0 < L < l_{\varphi} \leq l$. Note that $k_{\rm F}l \geq 1$ is called the Ioffe–Regel limit and the atomic Bohr radius $a_0 \ll \lambda_{\rm F}$.
- Landau Fermi liquid theory is concerned with the properties
 of many fermion systems at low temperature (much lower
 than Fermi energy) in the normal state, i.e. in the absence or
 at least at temperatures above any symmetry-breaking phase
 transition (superconduction, etc.).

References

- P.W. Anderson, Absence of diffusion in certain random lattice, Phys. Rev. 109 (1958), pp. 1492–1505; B. Kramer and A. MacKinnon, Localization: theory and experiment, Rep. Prog. Phys. 56 (1993), pp. 1469–1564.
- [2] E. Abrahams, P.W. Anderson, D.C. Licciardello, and T.V. Ramakrishnan, Scaling theory of localization: absence of quantum diffusion in two dimensions, Phys. Rev. Lett. 42 (1979), pp. 673–676; S. Roche, J. Jang, L. Foa Torres, and R. Saito, Charge transport in carbon nanotubes: quantum effects of electron-phonon coupling, J. Phys.: Condens. Matter 19 (2007), 183203.
- [3] D.M. Basko, I.L. Aleiner, and B.L. Altshuler, Metal-insulator transition in a weakly interacting many-electron system with localized single-particle states, Ann. Phys. 321 (2006), pp. 1126–1205.
- [4] Y. Imry, Introduction to Mesoscopic Physics, Oxford University Press, Oxford, 1997.
- [5] D.K. Ferry and S.M. Goodnick, Transport in Nanostructures, Cambridge University Press, Cambridge, 1997.
- [6] R Saito, G. Dresselhaus, and M.S. Dresselhaus, *Physical Properties of Carbon Nanotube*, Imperial College Press, London, 1998.
- [7] T. Ando, Theory of electronic states and transport in carbon nanotubes, J. Phys. Soc. Jpn. 74 (2005), pp. 777–815; J.-C. Charlier, X. Blase, and S. Roche, Electronic and transport properties of nanotubes, Rev. Mod. Phys. 79 (2007), pp. 677–732.
- [8] T. Giamarchi, Quantum Physics in One Dimension, Oxford University Press, Oxford, 2004.
- [9] M. Bockrath, D.H. Cobden, J. Lu, A.G. Rinler, R.E. Smalley, L. Balents, and P.L. McEuen, Luttinger-liquid behaviour in carbon nanotubes, Nature 397 (1999), pp. 598-601; J. Nygard, D.H. Cobden, M. Bockrath, P.L. McEuen, and P.E. Lindelof, Electrical transport measurements on single-walled carbon nanotubes, Appl. Phys. A 69 (1999), pp. 297-304.
- [10] J. Cao, Q. Wang, and H. Dai, Electron transport in very clean, as-grown suspended carbon nanotubes, Nat. Mater. 4 (2005), pp. 745–749.

- [11] G. Bergmann, Weak localization in thin films, Phy. Rep. 107 (1984), pp. 1–58.
- [12] I.V. Gornyi, A.D. Mirlin, and D.G. Poliakov, Electron transport in a disordered Luttinger liquid, Phys. Rev. B 75 (2007), 085421.
- [13] P. Mohanty and R.A. Webb, *Decoherence and quantum fluctuations*, Phys. Rev. B 55 (1997), p. R13452.
- [14] I.L. Aleiner, B.L. Altshuler, and M.E. Gershenson, *Interaction effects and phase relaxation in disordered systems*, Available at cond-mat/9808053
- [15] H. Bruus and K. Flensberg, Many-Body Quantum Theory in Condensed Matter Physics, An Introduction, Oxford University Press, Oxford, 2004.
- [16] B.L. Altshuler, A.G. Aronov, and D.E. Khmelnitskii, Effect of electron–electron collisions with small energy transfers on quantum localization, J. Phys. C 15 (1982), pp. 7367–7386.
- [17] Z. Yao, C.L. Kane, and C. Dekker, High-field electrical transport in single-wall carbon nanotubes, Phys. Rev. Lett. 84 (2000), pp. 2941–2944; J.-Y. Park, S. Rosenblatt, Y. Yaish, V. Sazonova, H. Ustunel, S. Braig, T.A. Arias, P.W. Brouwer, and P.L. McEuen, Electron-phonon scattering in metallic single-wall carbon nanotubes, Nano Lett. 4 (2004), pp. 517–520.
- [18] S. Roche, J. Jiang, F. Triozon, and R. Saito, *Quantum dephasing in carbon nanotubes due to electron-phonon coupling*, Phys. Rev. Lett. 95 (2005), 076803.
- [19] B. Sojetz, C. Miko, L. Forrò, and C. Strunk, Effect of band structure on quantum interference in multiwall carbon nanotubes, Phys. Rev. Lett. 94 (2005), 186802.
- [20] Y. Imry, O. Entin-Wohlman, and A. Aharony, *Landauer transport with inelastic scattering*, Europhys. Lett. 72 (2005), pp. 263–269.

Appendix A. LL: very brief review

A LL is a one-dimensional (Fermi liquid) correlated electron state characterised by a parameter g that measures the strength of the interaction between the electrons: strong repulsive interactions have $g \ll 1$, whereas g = 1 for the non-interacting electron gas (remembering that weakly interacting electrons in normal metal are described by quasi-particles of the Fermi liquid). The LLs are very special in that they retain a Fermi surface enclosing the same k-space volume as that of the free fermions, but there are no fermionic quasi-particles (like in normal Fermi liquids), their elementary excitations are bosonic collective charge and spin fluctuations dispersing with different velocities. An incoming electron decays into such charge and spin excitations, which then spatially separate with time (spincharge separation): the correlations between these excitations are anomalous and show up as interaction-dependent nonuniversal power laws in many physical properties, where those of ordinary metals are characterised by universal (interactionindependent) powers. A list of such properties includes: (1) a continuous momentum distribution function n(k), varying with as $|k - k_{\rm F}|^{\alpha}$ with an interaction-dependent exponent α , and a pseudogap in the single-particle density of states $\propto |\omega|^{\alpha}$, the consequences of the non-existence of fermionic quasi-particles; (2) similar power-law behaviour in all correlation functions (in those for charge or spin density-wave fluctuations) with universal scaling relations between the different non-universal exponents, which depend only on one effective coupling constant per degree of freedom; (3) finite spin and charge response at small wave vectors and finite Drude weight in the conductivity; (4) spin-charge separation; persistent currents quantised in units of $2k_{\rm F}$.